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FDP24N40 N-Channel UniFETTM MOSFET 400 V, 24 A, 175 mΩ

Features

- $R_{DS(on)}$ = 140 m Ω (Typ.) @ V_{GS} = 10 V, I_D = 12 A
- Low Gate Charge (Typ. 46 nC)
- Low C_{rss} (Typ. 25 pF)
- 100% Avalanche Tested
- RoHS Compliant

Applications

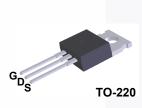
- Uninterruptible Power Supply
- AC-DC Power Supply

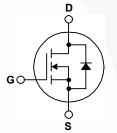
November 2013



Description

UniFETTM MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.





MOSFET Maximum Ratings T_C = 25°C unless otherwise noted.

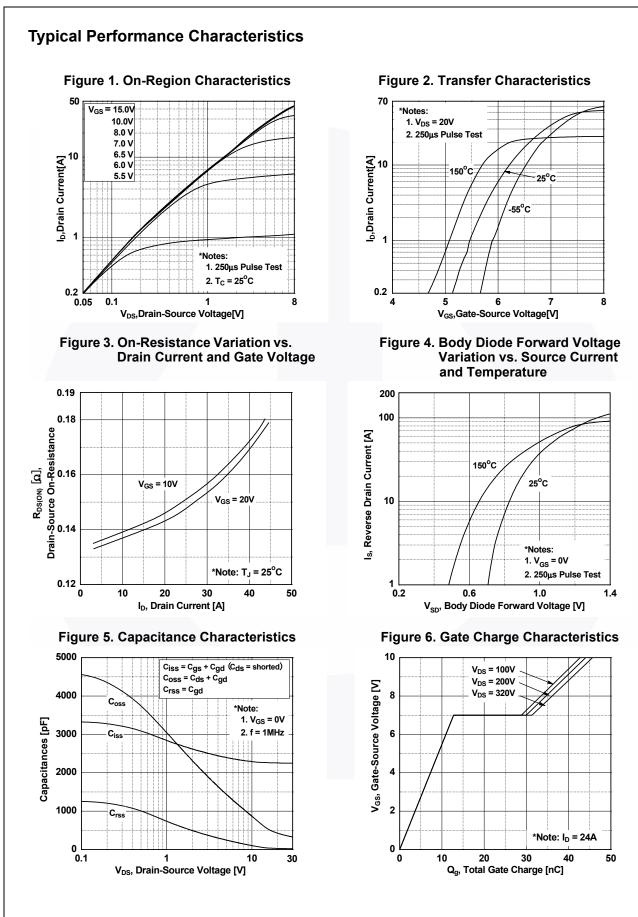
Symbol	Parameter		FDP24N40	Unit
V _{DSS}	Drain to Source Voltage	400	V	
V _{GSS}	Gate to Source Voltage		±30	V
ID	DrainCurrent	- Continuous (T _C = 25 ^o C)	24	Α
		- Continuous (T _C = 100 ^o C)	14.4	- A
I _{DM}	Drain Current	- Pulsed (Note	e 1) 96	Α
E _{AS}	Single Pulsed Avalanche	e 2) 1296	mJ	
I _{AR}	Avalanche Current	(Note	e 1) 24	Α
E _{AR}	Repetitive Avalanche Ene	rgy (Note	e 1) 22.7	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)		e 3) 4.5	V/ns
P _D	Dewer Dissingtion	(T _C = 25°C)	227	W
	Power Dissipation	- Derate Above 25°C	1.8	W/ºC
T _J , T _{STG}	Operating and Storage Te	-55 to +150	°C	
T _I	Maximum Lead Temperat	ure for Soldering, 1/8" from Case for 5 Seconds	300	°C

Thermal Characteristics

Symbol	Parameter	FDP24N40	Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	0.55	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient, Max.	62.5	0/00

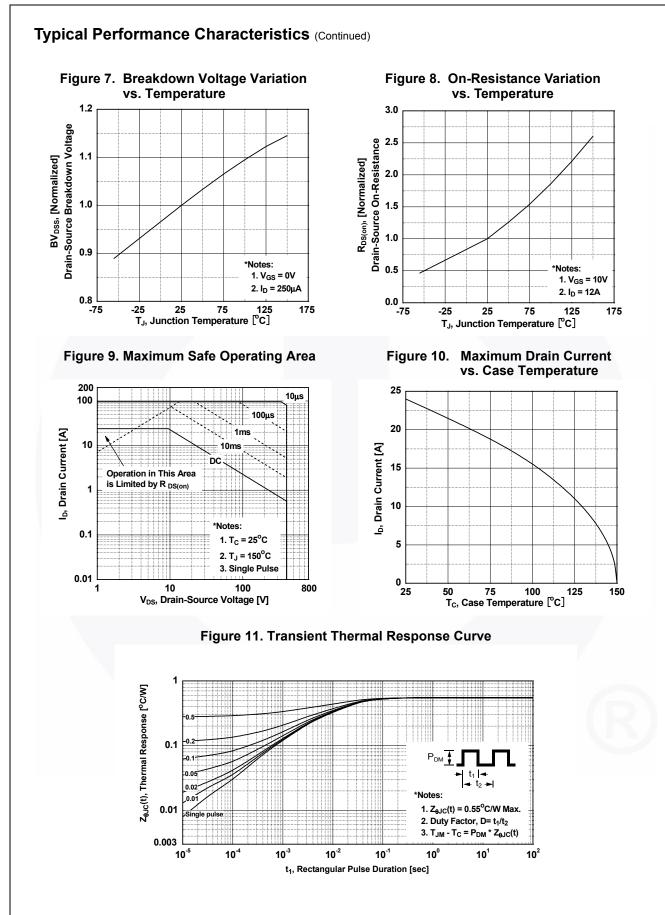
FDP24N40
- N-Channel
MOSFET

Part Nu	Part Number Top Mark P		Package	Packing Method	Reel Size) Т	ape Width	Qua	antity
•		TO-220	Tube	N/A		N/A	50 units		
Electrica	l Chara	cteristics T _c = 25°C	c unless oth	erwise noted.					
Symbol		Parameter		Test Conditions	s	Min.	Тур.	Max.	Unit
off Charge	toriotico								1
Off Charac	1				0-				
BV _{DSS}	Drain to Source Breakdown Voltage		I _D =	$I_D = 250 \ \mu A, \ V_{GS} = 0 \ V, \ T_J = 25^{\circ}C$		400	-	-	V
ΔΒV _{DSS} /ΔT _J	Breakdown Voltage Temperature Coefficient			$I_D = 250 \ \mu$ A, Referenced to 25° C		-	0.4	-	V/°C
	DSS Zero Gate Voltage Drain Current			$S = 400 V, V_{GS} = 0 V$		-	-	1	μA
				$_{\rm S}$ = 320 V, T _C = 125°C		-	-	10	
GSS	Gate to B	ody Leakage Current	V _G	$_{\rm S} = \pm 30 \text{ V}, \text{ V}_{\rm DS} = 0 \text{ V}$		-	-	±100	nA
On Charac	teristics								
V _{GS(th)}	-	eshold Voltage	Va	_S = V _{DS} , I _D = 250 μA		3.0	-	5.0	V
R _{DS(on)}		ain to Source On Resistance	-	$r_{S} = 10 \text{ V}, \text{ I}_{D} = 12 \text{ A}$		-	0.140	0.175	Ω
9 _{FS}		Transconductance		$_{\rm S} = 20$ V, $I_{\rm D} = 12$ A		-	34	-	S
9F5	. ormana		1.03	5 =0 1, 0 1=71			•••		
Dynamic C	haracter	istics							
C _{iss}	Input Cap	acitance	.,	05.11.11 0.11		-	2270	3020	pF
C _{oss}	Output Ca	apacitance		— V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz		-	365	490	pF
C _{rss}	Reverse ⁻	Transfer Capacitance				-	25	38	pF
Q _{g(tot)}	Total Gate	Fotal Gate Charge at 10V		V _{DS} = 320 V, I _D = 24 A,		-	46	60	nC
Q _{gs}	Gate to S	ource Gate Charge		$V_{\rm DS} = 320$ V, $I_{\rm D} = 24$ A, $V_{\rm GS} = 10$ V (Note 4)		-	12	-	nC
Q _{gd}	Gate to D	rain "Miller" Charge				-	20	-	nC
Switching	Characte	eristics							
-		Delay Time				-	40	90	ne
t _{d(on)}	Turn-On F	,	Vor	_D = 200 V, I _D = 24 A,	_	-	90	190	ns ns
t _r		Delay Time		$_{\rm S} = 10 \text{ V}, \text{ R}_{\rm G} = 25 \Omega$	-		110	230	ns
t _{d(off)} t _f	Turn-Off F	,			(Note 4)		65	140	ns
					(1010 4)	_		110	110
Drain-Soui	rce Diode	e Characteristics							
S	Maximum	Continuous Drain to Source	e Diode For	ward Current		-	-	24	Α
SM	Maximum	Pulsed Drain to Source Dic				-	-	96	Α
V _{SD}	Drain to S	ource Diode Forward Voltag		V _{GS} = 0 V, I _{SD} = 24 A		-	-	1.4	V
t _{rr}		Recovery Time	0.	_S = 0 V, I _{SD} = 24 A,		-	360	-	ns
Q _{rr}	Reverse F	Recovery Charge	dl _F /	/dt = 100 A/μs		-	4.7		μC



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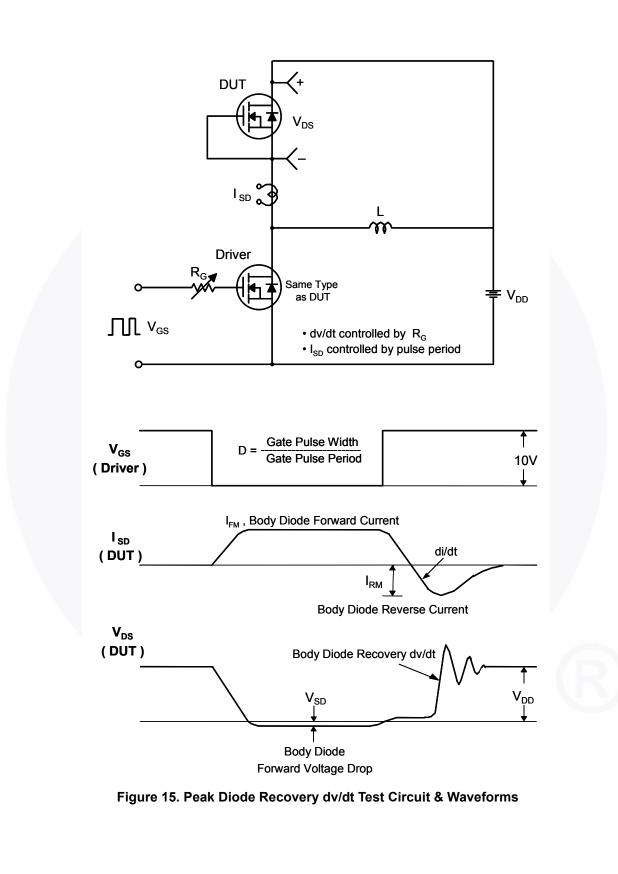


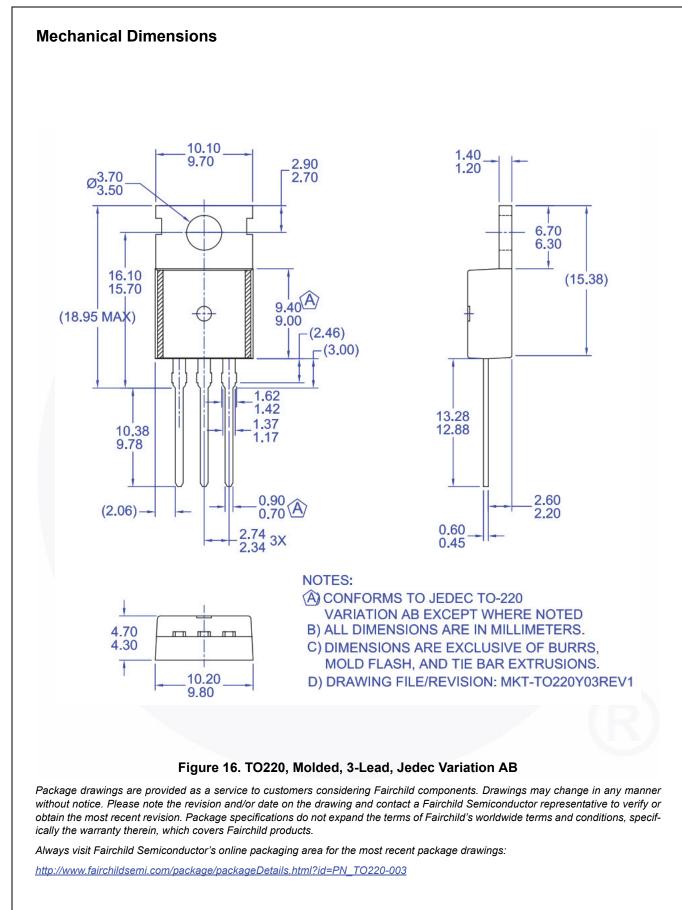
 V_{GS} ξ א Q_g FV_{DS} Q_{gd} Q_{gs} • DUT I_G = const. Charge Figure 12. Gate Charge Test Circuit & Waveform R VDS V_{DS} 90% ο V_{DD} GS R_{G} 10% V_{GS} DUT V_{GS} ∏ o Figure 13. Resistive Switching Test Circuit & Waveforms L $E_{AS} = \frac{1}{2} L I_{AS}^2$ V_{DS} $\mathsf{BV}_{\mathsf{DSS}}$ ID o I_{AS} R_{G} ŧν_{DD} $I_{D}(t)$ V_{GS}] $V_{DS}(t)$ V_{DD} DUT Time t_p Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

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